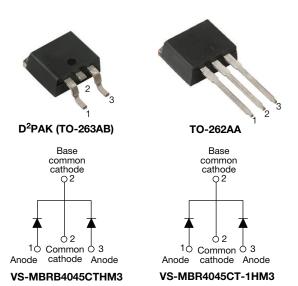
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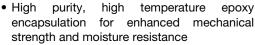
High Performance Schottky Rectifier, 2 x 20 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 x 20 A						
V_{R}	45 V					
V _F at I _F	0.58 V					
I _{RM} max.	95 mA at 125 °C					
T _J max.	150 °C					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					
E _{AS}	20 mJ					

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform (per device)	40	^					
I _{FRM}	T _C = 117 °C (per leg)	40	Α					
V_{RRM}		45	V					
I _{FSM}	t _p = 5 μs sine	900	Α					
V _F	20 A _{pk} , T _J = 125 °C	0.58	V					
TJ	Range	-65 to +150	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBRB4045CTHM3, VS-MBR4045CT-1HM3	UNITS				
Maximum DC reverse voltage	V_R	45	V				
Maximum working peak reverse voltage	V_{RWM}	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	ITIONS	VALUES	UNITS			
Maximum average per leg	l=	T_C = 118 °C, rated V_B		20				
forward current per device	I _{F(AV)}	TC = TT8 C, Tated VR		40				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz	Rated V _R , square wave, 20 kHz, T _C = 117 °C					
Maximum peak one cycle non-repetitive	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	900	A			
peak surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	210				
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 4.4 \text{mH}$		20	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	3	Α				



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS			
		20 A	T 05 °C	0.60				
Maximum forward valtage dres	V (1)	40 A	T _J = 25 °C	0.80	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T 105 %C	0.58				
		40 A	T _J = 125 °C	0.80				
		T _J = 25 °C		1	mA			
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 100 °C	Rated DC voltage	50				
reverse current		T _J = 125 °C		95				
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal I	900	pF				
Typical series inductance	L _S	Measured from top of	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _B					

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range	T_J		-65 to +150	°C			
Maximum storage temperature range	T _{Stg}		-65 to +175	O			
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (only for TO-220)	0.50	°C/W			
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK (TO-263AB) and TO-262AA)	50				
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm			
Mounting torque maximum		Non-jubricated tifreads	12 (10)	(lbf \cdot in)			
Marking daying		Case style D ² PAK (TO-263AB)	MBRB4	045CTH			
Marking device		Case style TO-262AA	MBR404	5CT-1H			

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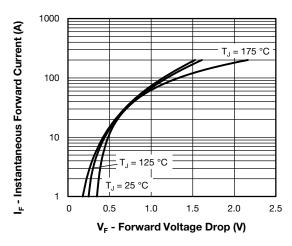


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

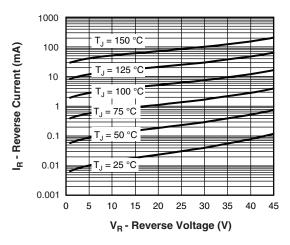


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

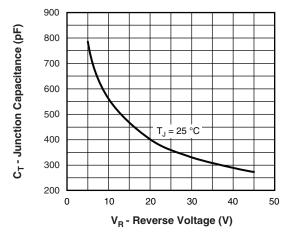


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

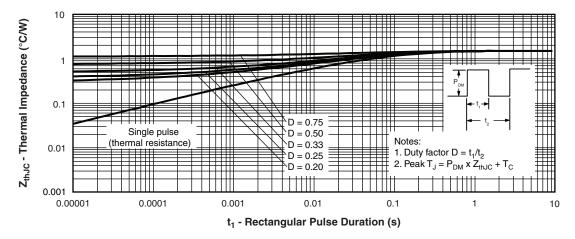


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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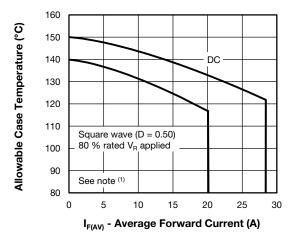


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

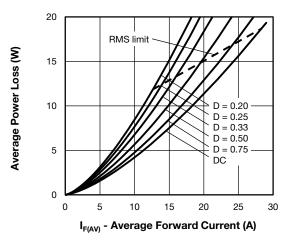


Fig. 6 - Forward Power Loss Characteristics

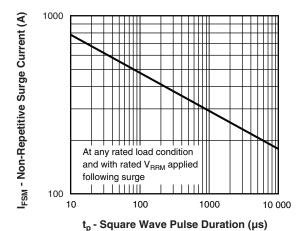


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

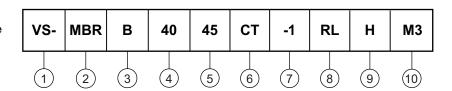
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; \ I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Essential part number

3 - • B = D^2PAK 7 None

• None = TO-262 **7** = -1

4 - Current rating (40 = 40 A)

- Voltage rating (45 = 45 V)

CT = Essential part number

- • None = D^2PAK 3 = B

• -1 = TO-262 **3** None

8 - • None = Tube

• L = Tape and reel (left oriented - for D²PAK only)

• R = Tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION								
VS-MBRB4045CTHM3	50	1000	Antistatic plastic tube					
VS-MBR4045CT-1HM3	50	1000	Antistatic plastic tube					
VS-MBRB4045CTLHM3	800	800	13" diameter reel					
VS-MBRB4045CTRHM3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Differsions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	D ² PAK (TO-263AB)	www.vishay.com/doc?95032				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOIES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

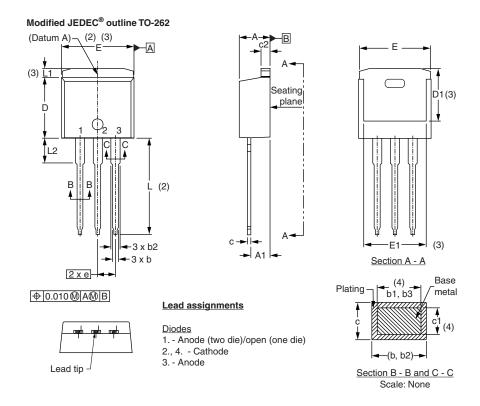
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	D BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019 1 Document Number: 95419



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